

General Description

The AOZ8030 is an 8-line device integrating EMI filtering with ESD protection for each line. It is designed to suppress unwanted EMI/RFI signals and provide electrostatic discharge (ESD) protection in portable electronic equipment. This state-of-the-art device utilizes AOS leading edge Trench Vertical Structure [TVS]²™ technology for superior clamping performance and filter attenuation over the full operating display range. The AOZ8030 has been optimized for protection of color LCD displays and CCD camera lines in cellular phones and other portable consumer electronic devices.

The AOZ8030 consists of eight identical circuits comprised of TVS diodes for ESD protection, and a resistor-capacitor network for EMI/RFI filtering. A series resistor value of 100Ω and a capacitance value of 28pF are used to achieve -35dB minimum attenuation from 800MHz to 3.0GHz. The TVS diodes provide effective suppression of ESD voltages in excess of ±20kV (air discharge) and ±20kV (contact discharge). This exceeds IEC 61000-4-2, level 4 ESD immunity test.

The AOZ8030 comes in an RoHS compliant, 1.2mm x 3.5mm, 0.4mm pitch DFN package and is rated over a -40°C to +85°C ambient temperature range.

Features

- 8 lines for EMI filtering and ESD protection:
 - Exceeds IEC 61000-4-2, level 4 (ESD) immunity test
 - ±20kV (air discharge) and ±20kV (contact discharge)
- Trench Vertical Structure [TVS]²™ based technology used to achieve excellent ESD clamping & filter performance over the full operating display range
- Filter performance: -35dB attenuation from 800MHz to 3.0GHz
- Low operating voltage: 5.0V
- Capacitance stability over wide range of voltages and temperatures
- DFN package: 1.2mm x 3.5mm, 0.4mm pitch
- Pb-Free device
- Green product

Applications

- EMI filtering and ESD protection for data lines
- LCD displays, camera interface, I/O interface
- Portable handheld devices, cell phones, PDA phones



Typical Application

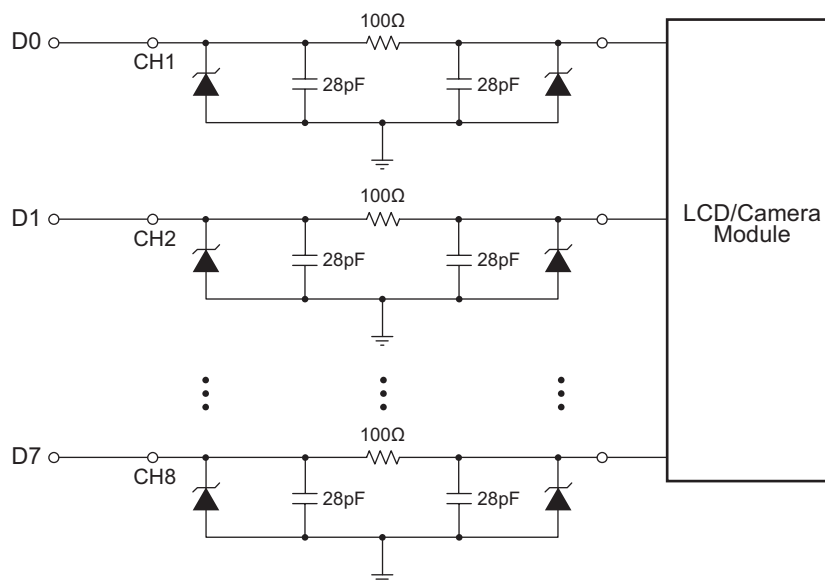


Figure 1

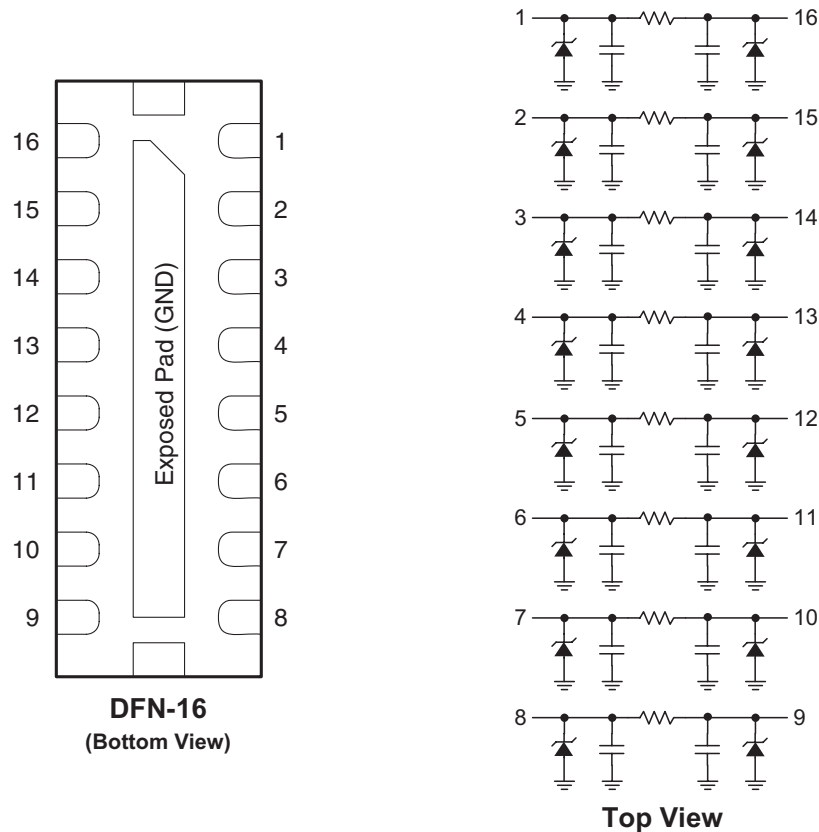
Ordering Information

Part Number	Ambient Temperature Range	Package	Environmental
AOZ8030DIL	-40°C to +85°C	DFN-16	RoHS Compliant Green Product



All AOS products are offered in packages with Pb-free plating and compliant to RoHS standards. Parts marked as Green Products (with "L" suffix) use reduced levels of Halogens, and are also RoHS compliant. Please visit www.aosmd.com/web/quality/rohs_compliant.jsp for additional information.

Pin Configuration



Pin Description

Pin Number	Pin Name	Pin Function
1,16	CH 1	Channel 1 Connections
2, 15	CH 2	Channel 2 Connections
3, 14	CH 3	Channel 3 Connections
4, 13	CH 4	Channel 4 Connections
5, 12	CH 5	Channel 5 Connections
6, 11	CH 6	Channel 6 Connections
7, 10	CH 7	Channel 7 Connections
8, 9	CH 8	Channel 8 Connections
Exposed Pad	GND	Common Ground Connection

Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	Rating
Storage Temperature (T _S)	-65°C to +150°C
ESD Rating per IEC61000-4-2, contact ⁽¹⁾	±20kV
ESD Rating per IEC61000-4-2, air ⁽¹⁾	±20kV
ESD Rating per Human Body Model ⁽²⁾	±30kV

Notes:

1. IEC 61000-4-2 discharge with C_{Discharge} = 150pF, R_{Discharge} = 330Ω.
2. Human Body Discharge per MIL-STD-883, Method 3015 C_{Discharge} = 100pF, R_{Discharge} = 1.5kΩ.

Electrical Characteristics

T_A = 25°C unless otherwise specified.

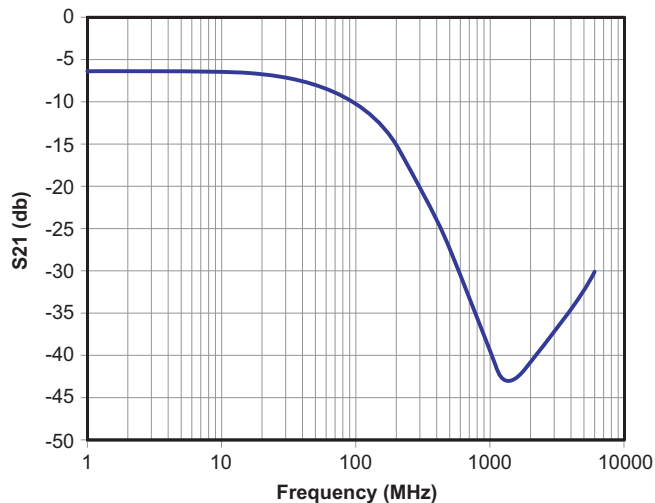
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V _{RWM}	Reverse Working Voltage	⁽³⁾			5.0	V
V _{BR}	Reverse Breakdown Voltage	I _T = 1mA ⁽⁴⁾	6	7	8	V
I _R	Reverse Leakage Current	V _{RWM} = 3.3V			0.1	μA
V _{CL}	Signal Clamp Voltage	I _{LOAD} = 1A, positive clamp ⁽⁵⁾⁽⁸⁾			7.00	V
		I _{LOAD} = 1A, negative clamp ⁽⁵⁾⁽⁸⁾			-3.00	
		I _{LOAD} = 5A, positive clamp ⁽⁵⁾⁽⁸⁾			8.00	
		I _{LOAD} = 5A, negative clamp ⁽⁵⁾⁽⁸⁾			-5.00	
		I _{LOAD} = 12A, positive clamp ⁽⁵⁾⁽⁸⁾			10.00	
		I _{LOAD} = 12A, negative clamp ⁽⁵⁾⁽⁸⁾			-10.00	
R _{CH}	Total Series Resistance	I _R = 20mA	90	100	110	Ω
C _{CH}	Channel Capacitance	Input to Ground ⁽⁶⁾⁽⁷⁾⁽⁸⁾	26	28	30	pF
f _C	Cut-off Frequency	Measured with 50Ω source and 50Ω load termination		90		MHz
	Attenuation from 800MHz to 3.0GHz	V _R = 0V Measured with 50Ω source and 50Ω load termination		-35		dB
	Attenuation from 800MHz to 3.0GHz	V _R = 5V Measured with 50Ω source and 50Ω load termination		-35		dB

Notes:

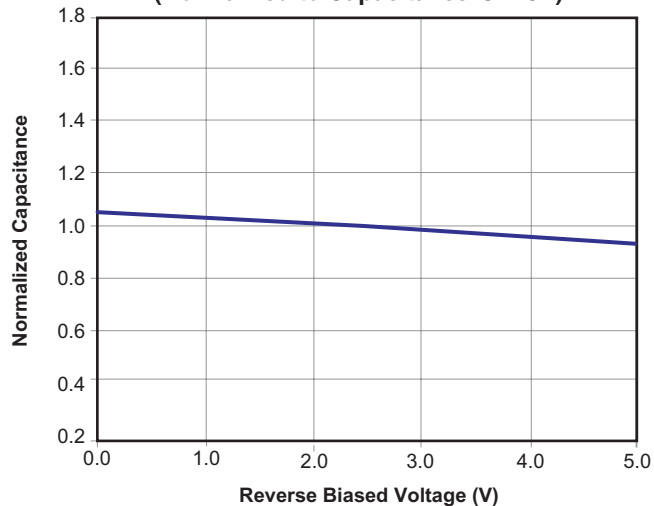
3. The working peak reverse voltage, V_{RWM}, should be equal to or greater than the DC or continuous peak operating voltage level.
4. V_{BR} is measured at the pulse test current I_T.
5. Measurements performed using a 100ns Transmission Line Pulse (TLP) system.
6. Total capacitance is equal to 2 x C_{CH}.
7. Measured at 25°C, V_R = 2.5V, f = 1.0MHz.
8. Guaranteed by design.

Typical Performance Characteristics

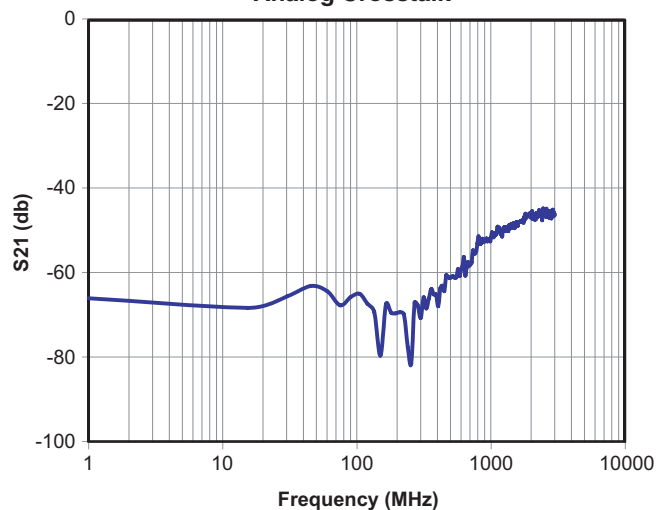
Insertion Loss Characteristics



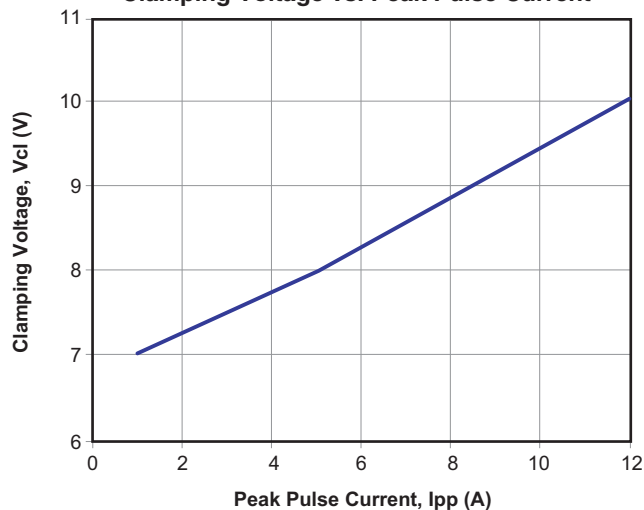
Typical Line Capacitance vs. Reverse Bias Voltage
(Normalized to Capacitance @ 2.5V)



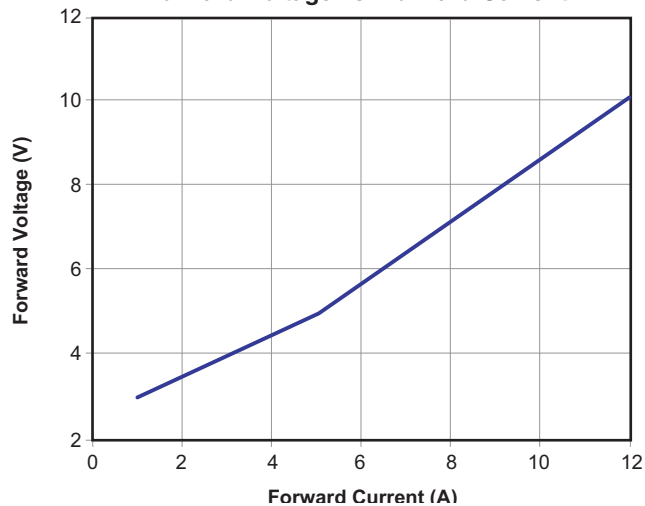
Analog Crosstalk



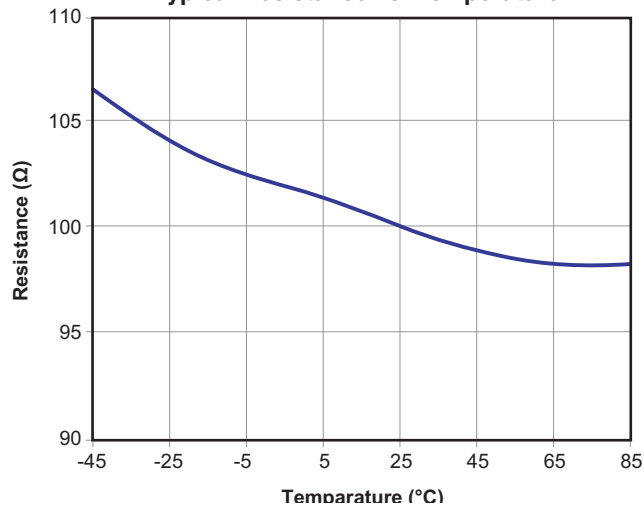
Clamping Voltage vs. Peak Pulse Current



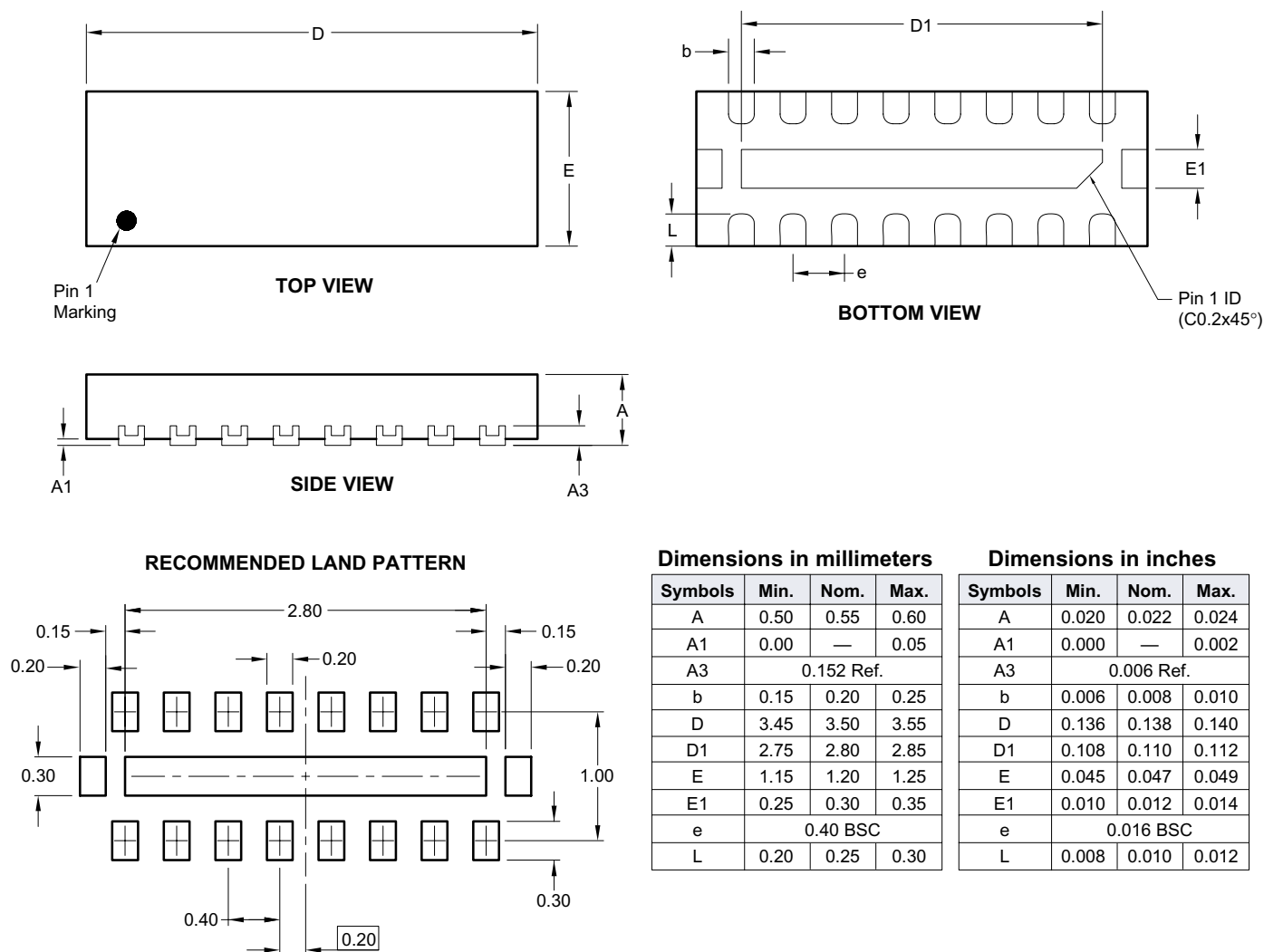
Forward Voltage vs. Forward Current



Typical Resistance vs. Temperature



Package Dimensions, DFN 3.5 x 1.2, 16L

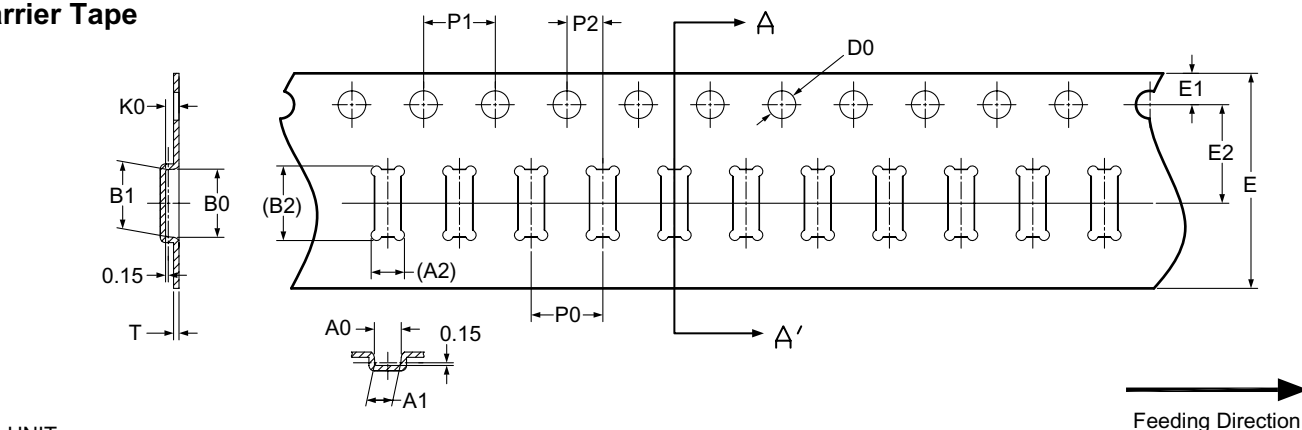


Notes:

1. All dimensions are in millimeters. Angles is degree.
2. Warpage shall not exceed 0.10mm.
3. Marking is for package orientation reference only.

Tape & Reel Dimensions, DFN 3.5 x 1.2, 16L

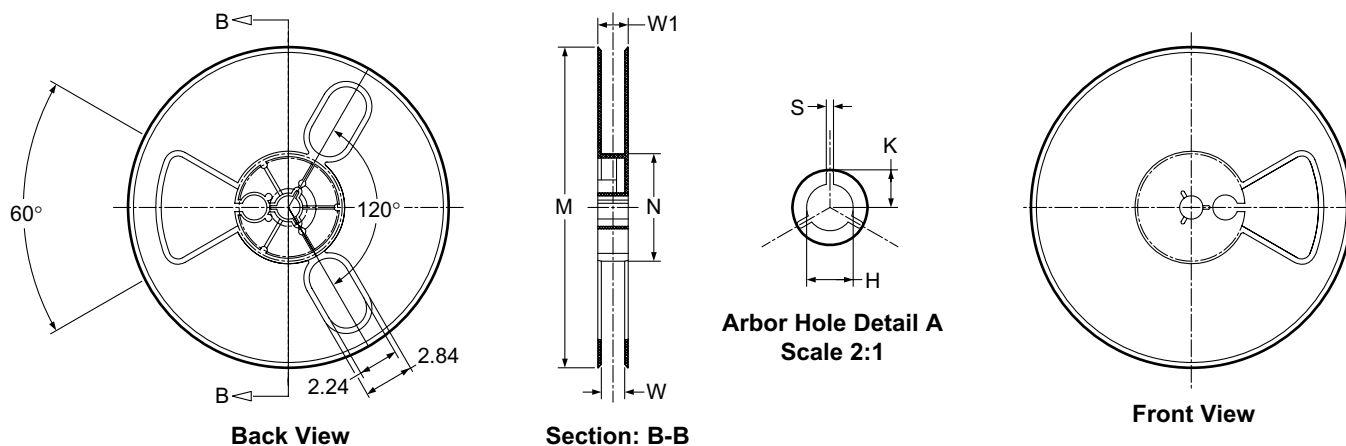
Carrier Tape



UNIT: mm

Package	T	B0	B1	B2	A0	A1	A2	K0	D0	E	E1	E2	P0	P1	P2
DFN 3.5x1.2	0.30 ±0.05	3.80 ±0.1	3.75 ±0.1	4.16	1.50 ±0.1	1.45 ±0.1	1.86	0.75 ±0.1	ø1.55 ±0.05	12.00 ±0.3	1.75 ±0.1	5.50 ±0.05	4.00 ±0.10	4.0 ±0.1	2.00 ±0.05

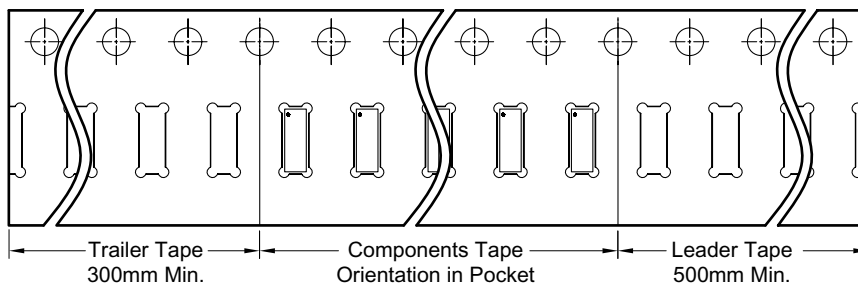
Reel



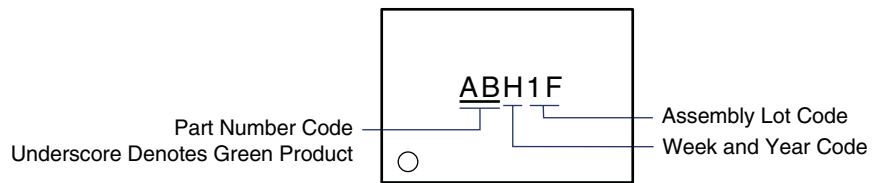
Unit: mm

Tape Size	Reel Size	M	N	W	W1	H	K	S
12mm	ø1800	ø179.0 +1.0	ø60.0 ±0.5	13.0 ±0.5	17.0	ø13.0 ±0.2	10.5 ±0.25	1.8 (Bottom)

Leader/Trailer & Orientation



Package Marking



This data sheet contains preliminary data; supplementary data may be published at a later date. Alpha & Omega Semiconductor reserves the right to make changes at any time without notice.

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As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.